

JFW

XA-9947
PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of:

Nobuyuki SUGII et al.

Appln. No.: 10/673,789

Group Art Unit: 2814

Filed: September 30, 2004

Examiner: L. Pham

For: INSULATED-GATE FIELD-EFFECT TRANSISTOR, METHOD OF
FABRICATING THE SAME, AND SEMICONDUCTOR DEVICE EMPLOYING
THE SAME

* * *

RESPONSE

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

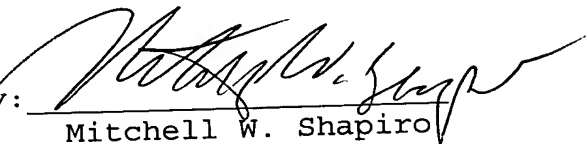
Sir:

Responding to the Office Action mailed February 9,
2005, and to the requirement for election of species
therein, Applicants elect Species 2 (Claims 8-18) for
prosecution on the merits. An action on the merits is
respectfully requested.

The Commissioner is hereby authorized to charge to
Deposit Account No. 50-1165 any fees under 37 C.F.R. §§1.16
and 1.17 which may be required by this paper, and to credit

any overpayment to that Account. If any extension of time is required in connection with the filing of this paper and has not been requested separately, then such extension is hereby requested.

Respectfully submitted,

By: 
Mitchell W. Shapiro
Reg. No. 31,568

MWS:kss

Miles & Stockbridge P.C.
1751 Pinnacle Drive
Suite 500
McLean, Virginia 22102
(703) 903-9000

February 24, 2005